

ANSALDO**Ansaldo Trasporti s.p.a.
Unita' Semiconduttori**Via N. Lorenzi 8 - I 16152 GENOVA - ITALY
Tel. int. +39/(0)10 6556549 - (0)10 6556488
Fax Int. +39/(0)10 6442510
Tx 270318 ANSUSE I -**FAST RECOVERY DIODE****ARF322**

Repetitive voltage up to

1600 V

Mean forward current

740 A

Surge current

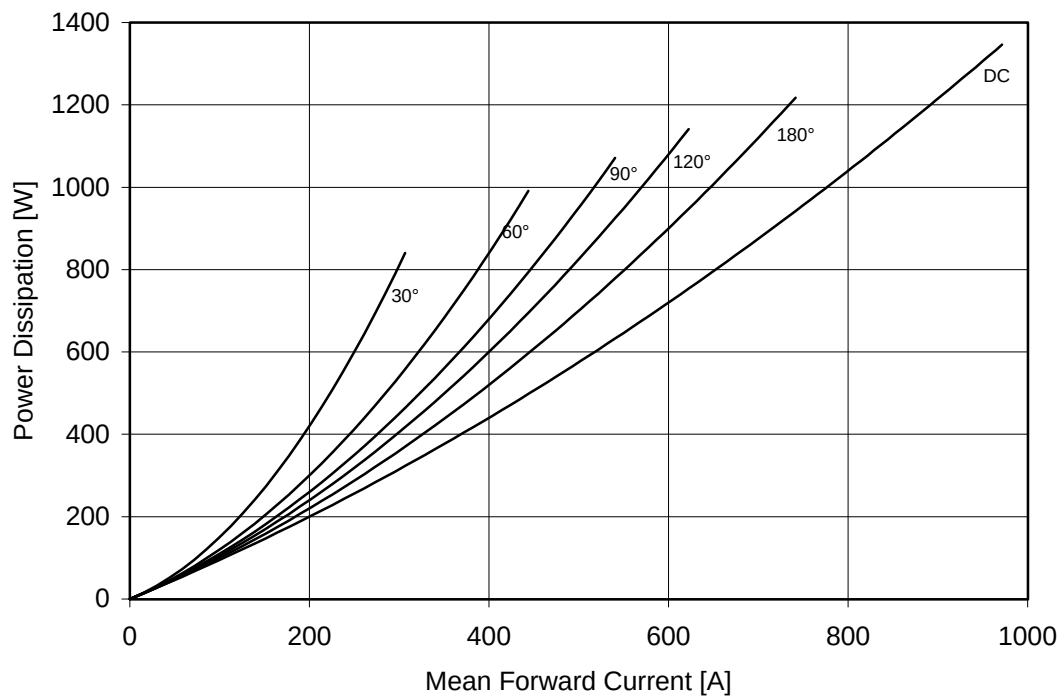
11 kA**FINAL SPECIFICATION**

ott 97 - ISSUE : 04

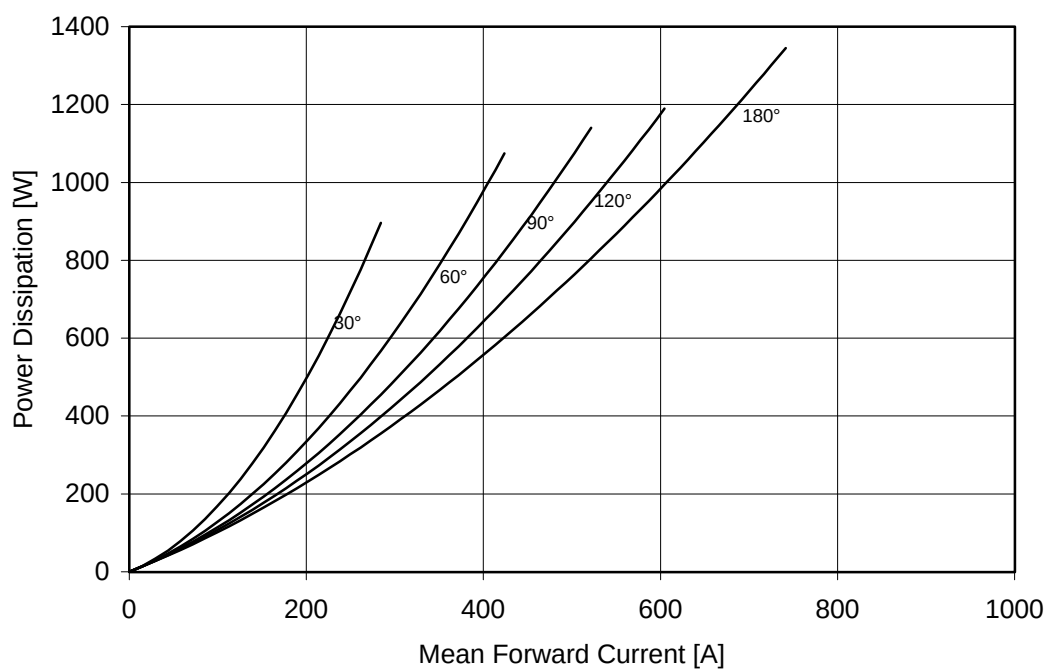
Symbol	Characteristic	Conditions	T _j [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		125	1600	V
V _{RSM}	Non-repetitive peak reverse voltage		125	1700	V
I _{RRM}	Repetitive peak reverse current	V=VRRM	125	50	mA
CONDUCTING					
I _{F (AV)}	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		740	A
I _{F (AV)}	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		740	A
I _{FSM}	Surge forward current	Sine wave, 10 ms	125	11	kA
I ² t	I ² t	reapplied reverse voltage up to 50% VRSM		605 x1E3	A²s
V _{FM}	Forward voltage	Forward current 1200 A	25	1.65	V
V _{F(TO)}	Threshold voltage		125	0.90	V
r _F	Forward slope resistance		125	0.500	mohm
SWITCHING					
t _{rr}	Reverse recovery time	I _F = 1000 A di/dt= 60 A/µs VR = 50 V	125	2.0	µs
Q _{rr}	Reverse recovery charge			60	µC
I _{rr}	Peak reverse recovery current			70	A
s	Softness (s-factor), min			0.5	
V _{FR}	Peak forward recovery	di/dt= 100 A/µs		4	V
MOUNTING					
R _{th(j-h)}	Thermal impedance	Junction to heatsink, double side cooled		52	°C/kW
T _j	Operating junction temperature			-30 / 125	°C
F	Mounting force			8.4 / 9.4	kN
	Mass			280	g
ORDERING INFORMATION : ARF322 S 16					
standard specification ☐ ☐ VRRM/100					

DISSIPATION CHARACTERISTICS

SQUARE WAVE

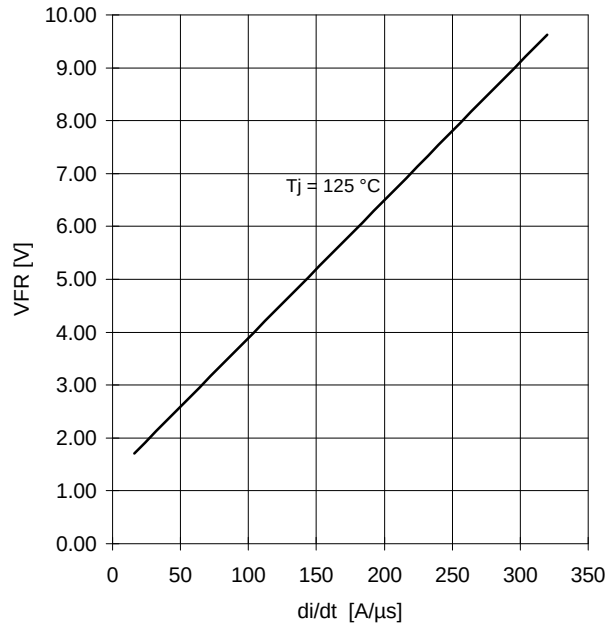
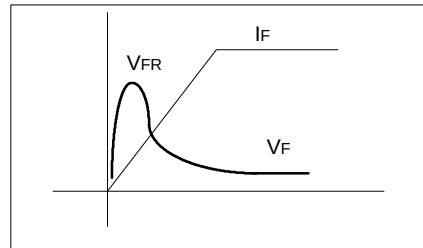


SINE WAVE



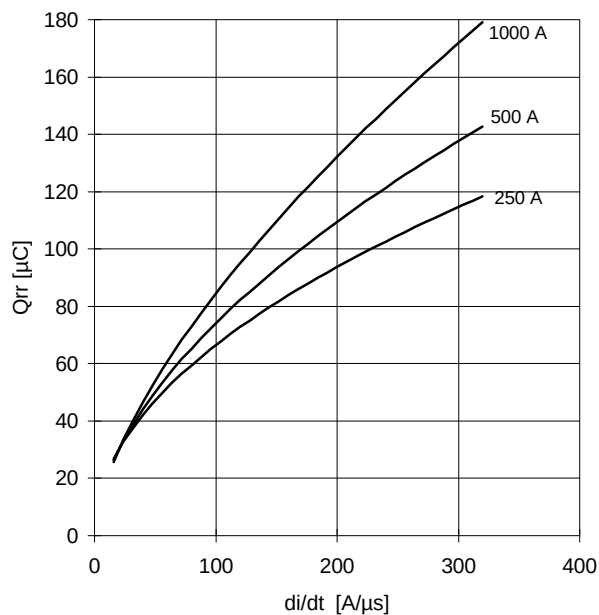
SWITCHING CHARACTERISTICS

FORWARD RECOVERY VOLTAGE



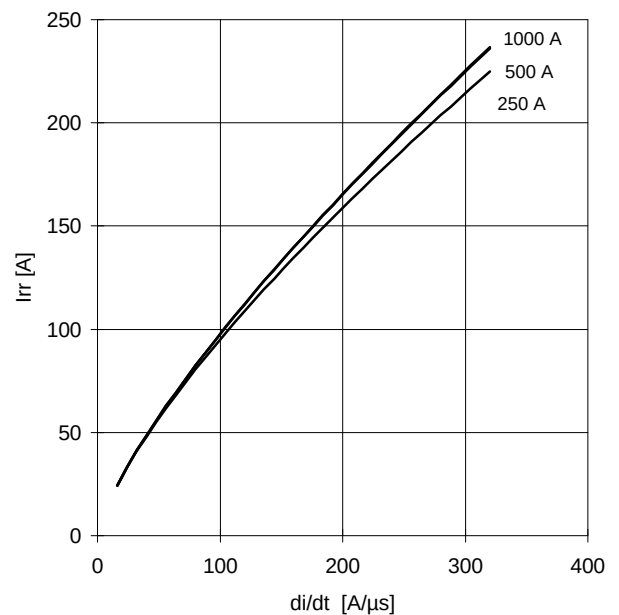
REVERSE RECOVERY CHARGE

$T_j = 125\text{ }^{\circ}\text{C}$



REVERSE RECOVERY CURRENT

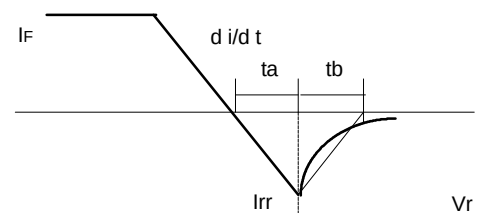
$T_j = 125\text{ }^{\circ}\text{C}$



$$t_a = I_{rr} / (di/dt) \quad t_b = t_{rr} - t_a$$

$$\text{Softness (s factor)} \quad s = t_b / t_a$$

$$\text{Energy dissipation during recovery } E_r = V_r \cdot (Q_{rr} - I_{rr} \cdot t_a / 2)$$

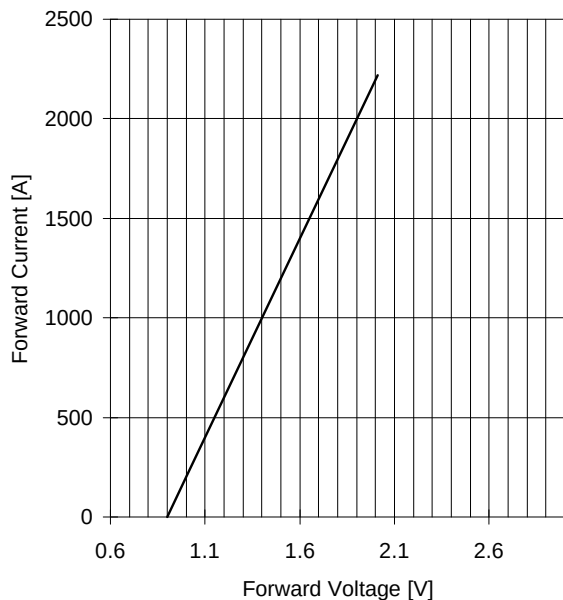


ARF322 FAST RECOVERY DIODE

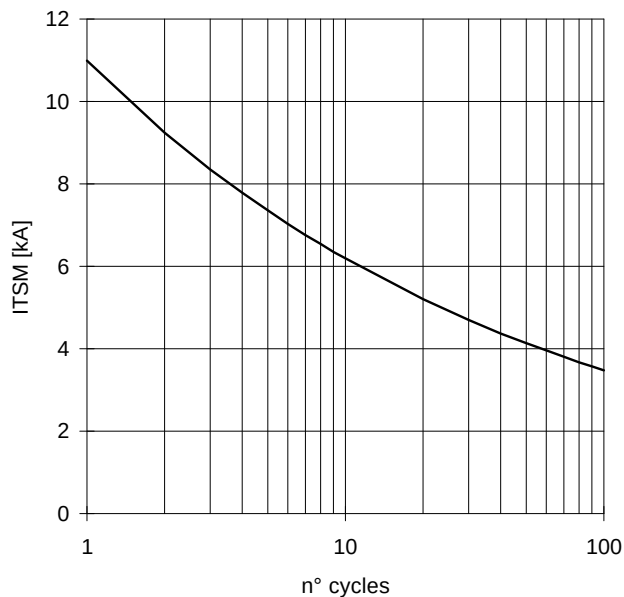
ANSALDO

FINAL SPECIFICATION ott 97 - ISSUE : 04

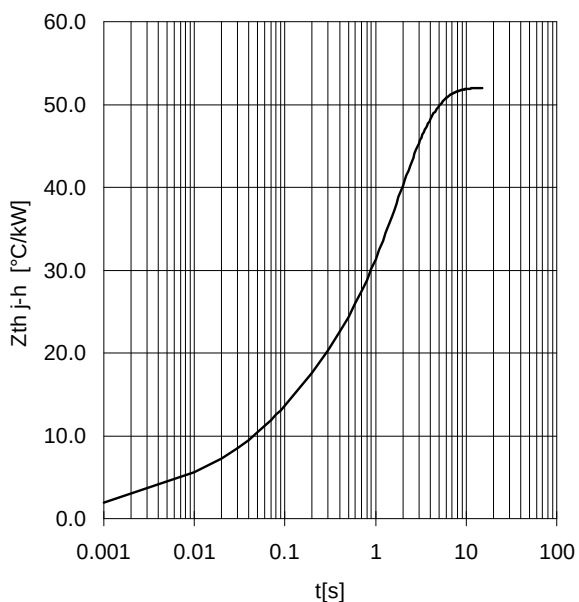
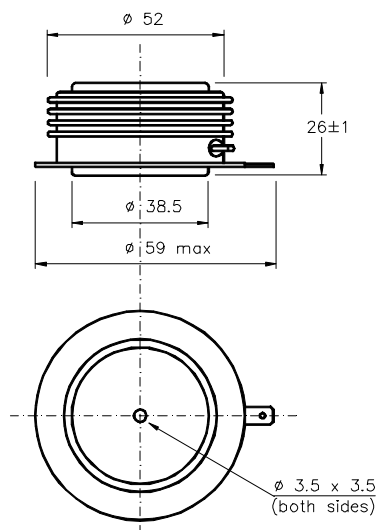
FORWARD CHARACTERISTIC
 $T_j = 125^\circ\text{C}$



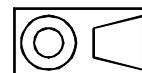
SURGE CHARACTERISTIC
 $T_j = 125^\circ\text{C}$



TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED



Dimensions
in mm



All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness $< .03$ mm and roughness $< 2 \mu\text{m}$.

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

Distributed by

